

# International **IR** Rectifier

SCHOTTKY RECTIFIER

**100BGQ015**  
**100BGQ015J**

100 Amp

**Major Ratings and Characteristics**

Characteristics	100BGQ015	Units
$I_{F(AV)}$ Rectangular waveform @ $T_C$	100 91	A °C
$I_{DC}$ Maximum	141	A
$V_{RRM}$	15	V
$I_{FSM}$ @ $t_p=5\mu s$ sine	5000	A
$V_F$ @ 100Apk typical @ $T_J$	0.38 125	V °C
$T_J$ range	-55 to 125	°C

**Description/ Features**

The 100BGQ015 Schottky rectifier has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125° C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

- 125°C  $T_J$  operation ( $V_R < 5V$ )
- Optimized for OR-ing applications
- High frequency operation
- Ultra low forward voltage drop
- Continuous High Current operation
- Guard ring for enhanced ruggedness and long term reliability
- **PowIRtab™ package**

**Case Styles**

100BGQ015	100BGQ015J

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**Voltage Ratings**

Part number		100BGQ015	
$V_R$	Max. DC Reverse Voltage (V) @ $T_J = 100^\circ\text{C}$		15
$V_R$	Max. DC Reverse Voltage (V) @ $T_J = 125^\circ\text{C}$		5

**Absolute Maximum Ratings**

Parameters	100BGQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	100	A	50% duty cycle @ $T_C = 91^\circ\text{C}$ , rectangular wave form
$I_{F(RMS)}$ RMS Forward Current	141	A	$T_C = 88^\circ\text{C}$
$I_{FSM}$ Max. PeakOneCycleNon-Repetitive SurgeCurrent	5000	A	5μs Sine or 3μs Rect. pulse
	1000		10ms Sine or 6ms Rect. pulse
$E_{AS}$ Non-Repetitive Avalanche Energy	9	mJ	$T_J = 25^\circ\text{C}$ , $I_{AS} = 2$ Amps, $L = 4.5$ mH
$I_{AR}$ Repetitive Avalanche Current	2	A	Current decaying linearly to zero in 1 μsec Frequency limited by $T_J$ max. $V_A = 3 \times V_R$ typical

**Electrical Specifications**

Parameters	100BGQ		Units	Conditions		
	Typ.	Max.				
$V_{FM}$ Forward Voltage Drop (1) (2)	0.34	0.37	V	@ 50A	$T_J = 25^\circ\text{C}$	
	0.42	0.46	V	@ 100A		
	0.26	0.29	V	@ 50A	$T_J = 125^\circ\text{C}$	
	0.38	0.42	V	@ 100A		
$I_{RM}$ Reverse Leakage Current (1)	7	18	mA	$T_J = 25^\circ\text{C}$	$V_R = \text{rated } V_R$	
	580	870	mA	$T_J = 100^\circ\text{C}$		
	480	700	mA	$T_J = 100^\circ\text{C}$ $V_R = 12$ V	$T_J = 125^\circ\text{C}$ $V_R = 5$ V	
	1	1.2	A			
$V_{F(TO)}$ Threshold Voltage	0.155		V	$T_J = T_J \text{ max.}$		
$r_t$ Forward Slope Resistance	2.45		$\text{m}\Omega$			
$C_T$ Max. Junction Capacitance	3800		pF	$V_R = 5V_{DC}$ , (test signal range 100Khz to 1Mhz) $25^\circ\text{C}$		
$L_s$ Typical Series Inductance	3.5		nH	Measured from tab to mounting plane		
$dv/dt$ Max. Voltage Rate of Change (Rated $V_R$ )	10000		V/ μs			

(1) Pulse Width &lt; 300μs, Duty Cycle &lt; 2%

(2)  $V_{FM} = V_{F(TO)} + r_t \times I_F$ **Thermal-Mechanical Specifications**

Parameters	100BGQ	Units	Conditions
$T_J$ Max. Junction Temperature Range	-55 to 125	°C	
$T_{stg}$ Max. Storage Temperature Range	-55 to 150	°C	
$R_{thJC}$ Max. Thermal Resistance Junction to Case	0.50	°C/W	DC operation
$R_{thCS}$ Typical Thermal Resistance, Case to Heatsink	0.20	°C/W	Mounting surface, smooth and greased
wt Approximate Weight	5(0.18)	g(oz.)	
T Mounting Torque	Min.	1.2(10)	N*m (lbf-in)
	Max.	2.4(20)	
Case Style	$PowRtab^{\text{TM}}$		

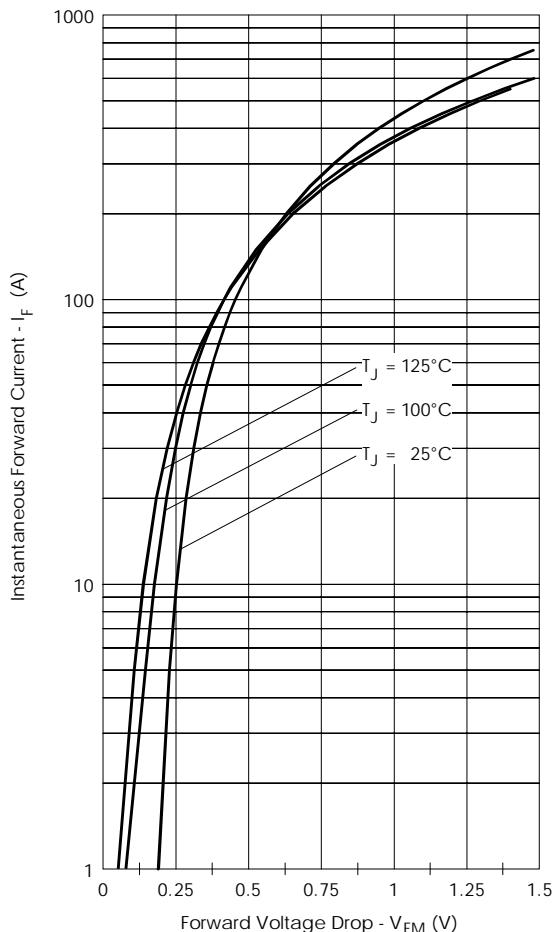


Fig.1-Maximum Forward Voltage Drop Characteristics

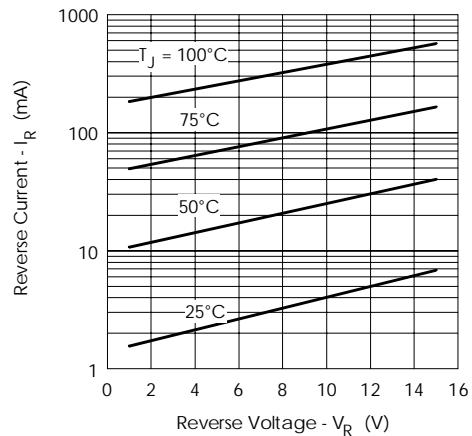


Fig.2-Typical Values of Reverse Current Vs. Reverse Voltage

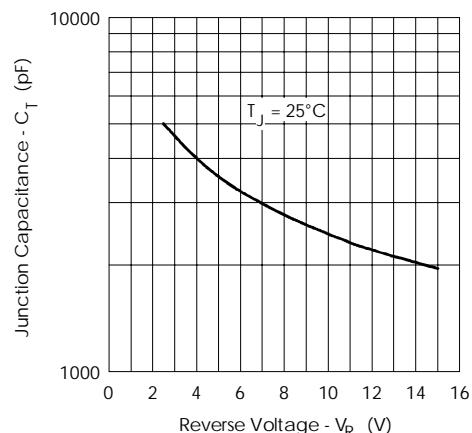


Fig.3-Typical Junction Capacitance Vs. Reverse Voltage

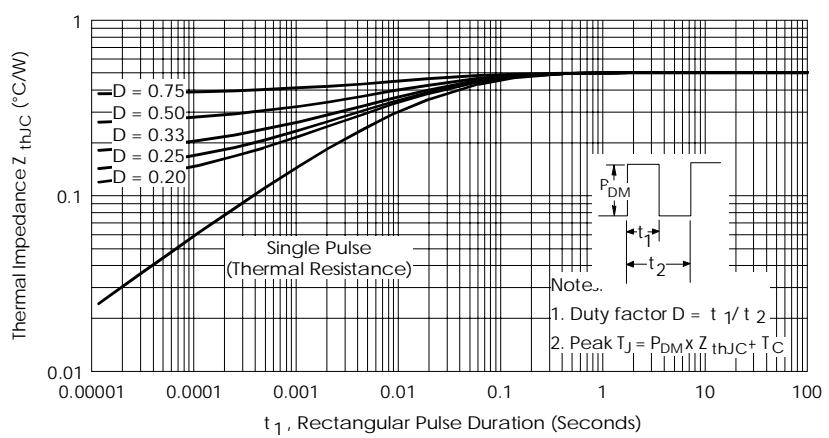


Fig.4-Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

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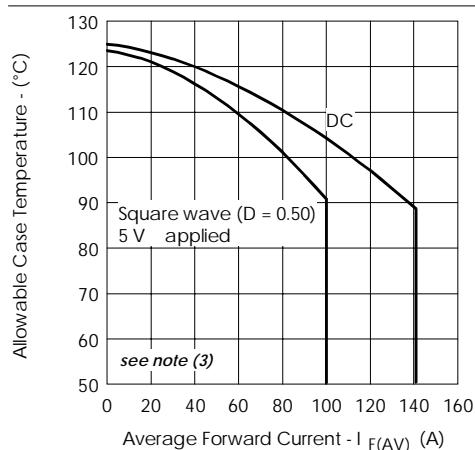


Fig. 5-Maximum Allowable Case Temperature Vs. Average Forward Current

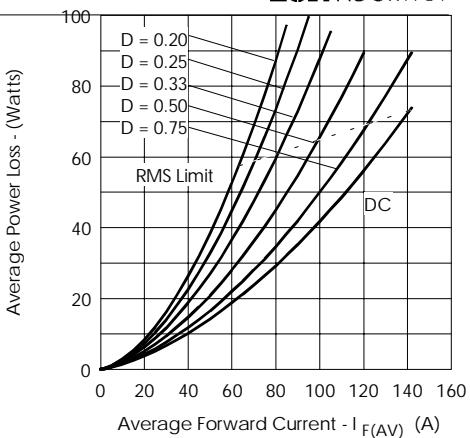


Fig. 6-Forward Power Loss Characteristics

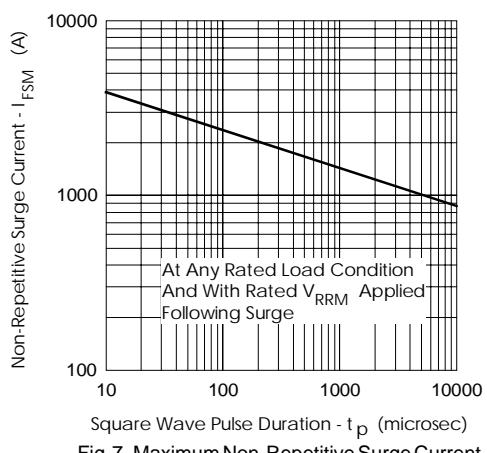


Fig. 7-Maximum Non-Repetitive Surge Current

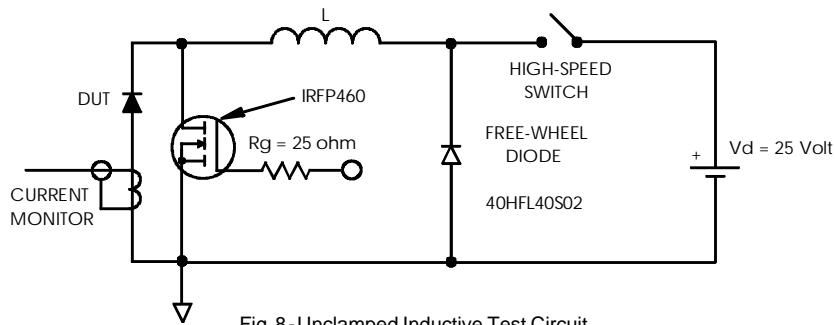


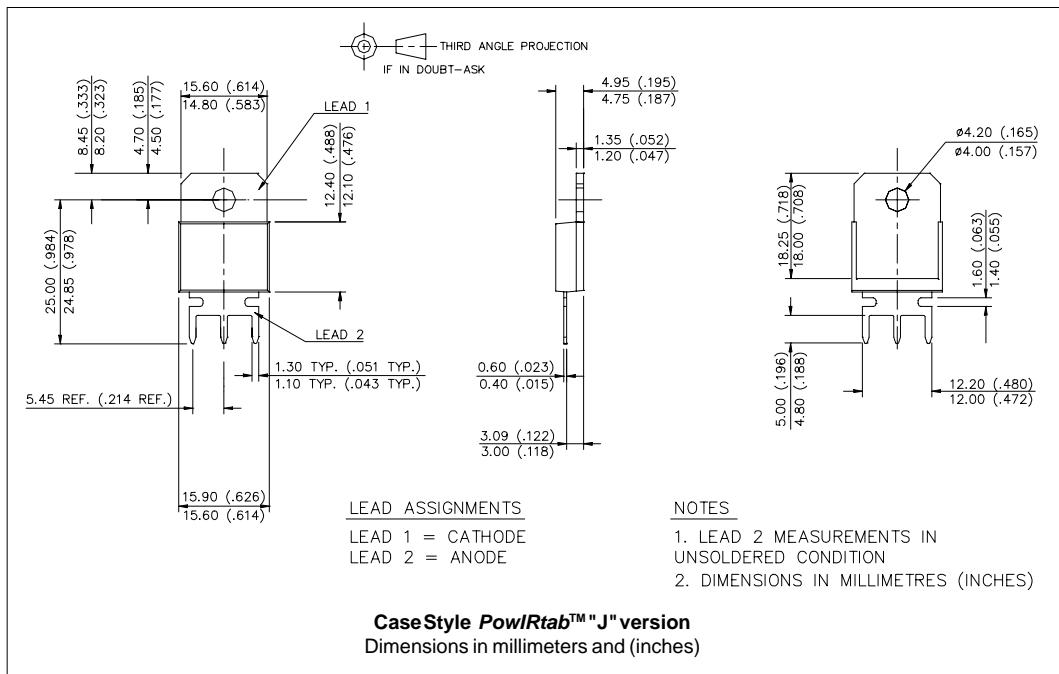
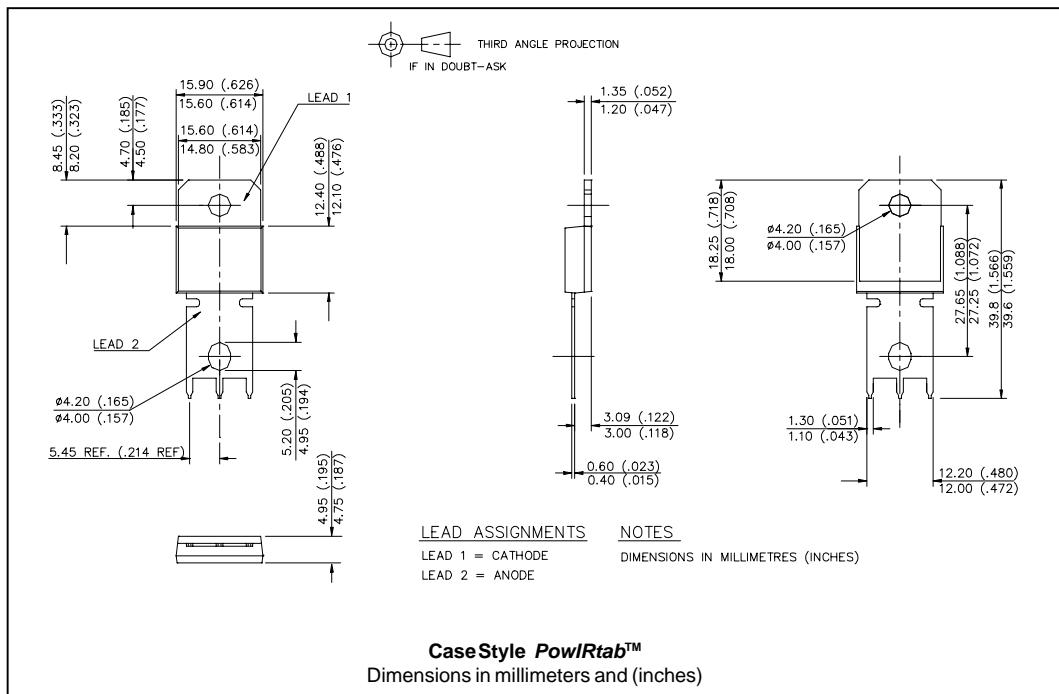
Fig. 8-Unclamped Inductive Test Circuit

(3) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;

$P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$  (see Fig. 6);

$P_{d_{REV}} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D); I_R @ V_{R1} = 80\% \text{ rated } V_R$

Outline Table



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Ordering Information Table

Device Code	100	BGQ	015	J
	1	2	3	4
1 - Current Rating				
2 - Essential Part Number				
3 - Voltage code: Code = V <sub>RRM</sub>				
4 - none = PowIRtab™ standard				
J = Short Lead Version				

Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial Level.  
Qualification Standards can be found on IR's Web site.

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